Brushless DC Motor Controller

The MC33035 is a high performance second generation monolithic brushless DC motor controller containing all of the active functions required to implement a full featured open loop, three or four phase motor control system. This device consists of a rotor position decoder for proper commutation sequencing, temperature compensated reference capable of supplying sensor power, frequency programmable sawtooth oscillator, three open collector top drivers, and three high current totem pole bottom drivers ideally suited for driving power MOSFETs.

Also included are protective features consisting of undervoltage lockout, cycle-by-cycle current limiting with a selectable time delayed latched shutdown mode, internal thermal shutdown, and a unique fault output that can be interfaced into microprocessor controlled systems.

Typical motor control functions include open loop speed, forward or reverse direction, run enable, and dynamic braking. The MC33035 is designed to operate with electrical sensor phasings of $60^{\circ}/300^{\circ}$ or $120^{\circ}/240^{\circ}$, and can also efficiently control brush DC motors.

Features

- 10 to 30 V Operation
- Undervoltage Lockout
- 6.25 V Reference Capable of Supplying Sensor Power
- Fully Accessible Error Amplifier for Closed Loop Servo Applications
- High Current Drivers Can Control External 3-Phase MOSFET Bridge
- Cycle–By–Cycle Current Limiting
- Pinned-Out Current Sense Reference
- Internal Thermal Shutdown
- Selectable 60°/300° or 120°/240° Sensor Phasings
- Can Efficiently Control Brush DC Motors with External MOSFET H–Bridge
- NCV Prefix for Automotive and Other Applications Requiring Site and Control Changes
- Pb-Free Packages are Available



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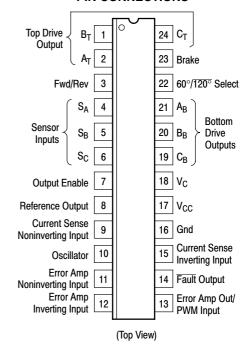
P SUFFIX PLASTIC PACKAGE CASE 724



DW SUFFIXPLASTIC PACKAGE
CASE 751E
(SO-24L)



PIN CONNECTIONS



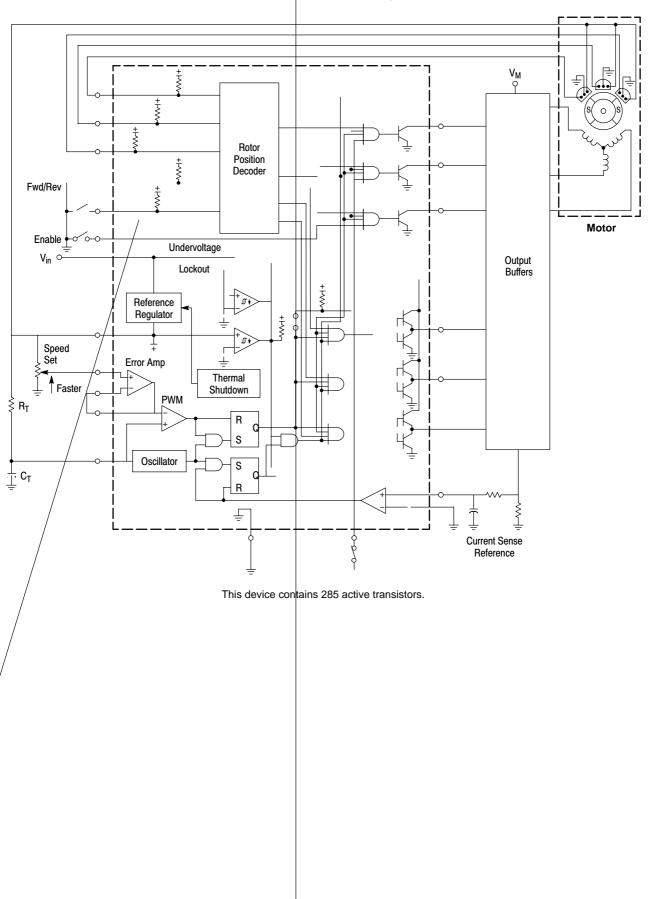
ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 27 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 27 of this data sheet.

Representative Schematic Diagram



MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Voltage	V _{CC}	40	V
Digital Inputs (Pins 3, 4, 5, 6, 22, 23)	-	V _{ref}	V
Oscillator Input Current (Source or Sink)	losc	30	mA
Error Amp Input Voltage Range (Pins 11, 12, Note 1)	V _{IR}	−0.3 to V _{ref}	V
Error Amp Output Current (Source or Sink, Note 2)	l _{Out}	10	mA
Current Sense Input Voltage Range (Pins 9, 15)	V _{Sense}	-0.3 to 5.0	V
Fault Output Voltage	V _{CE(Fault)}	20	V
Fault Output Sink Current	I _{Sink(Fault)}	20	mA
Top Drive Voltage (Pins 1, 2, 24)	V _{CE(top)}	40	V
Top Drive Sink Current (Pins 1, 2, 24)	I _{Sink(top)}	50	mA
Bottom Drive Supply Voltage (Pin 18)	V _C	30	V
Bottom Drive Output Current (Source or Sink, Pins 19, 20, 21)	I _{DRV}	100	mA
Power Dissipation and Thermal Characteristics P Suffix, Dual In Line, Case 724 Maximum Power Dissipation @ T _A = 85°C Thermal Resistance, Junction–to–Air DW Suffix, Surface Mount, Case 751E Maximum Power Dissipation @ T _A = 85°C Thermal Resistance, Junction–to–Air	P _D R _{θJA} P _D R _{θJA}	867 75 650 100	mW °C/W mW °C/W
Operating Junction Temperature	TJ	150	°C
Operating Ambient Temperature Range (Note 3) MC33035 NCV33035	T _A	-40 to +85 -40 to +125	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ELECTRICAL CHARACTERISTICS ($V_{CC} = V_C = 20 \text{ V}$, $R_T = 4.7 \text{ k}$, $C_T = 10 \text{ nF}$, $T_A = 25 ^{\circ}\text{C}$, unless otherwise noted.)

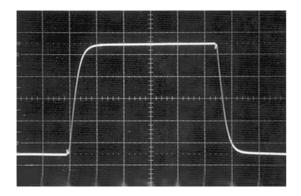
Characteristic	Symbol	Min	Тур	Max	Unit				
REFERENCE SECTION									
Reference Output Voltage ($I_{ref} = 1.0 \text{ mA}$) $T_A = 25^{\circ}\text{C}$ (Note 4)	V _{ref}	5.9 5.82	6.24 -	6.5 6.57	٧				
Line Regulation ($V_{CC} = 10 \text{ to } 30 \text{ V}, I_{ref} = 1.0 \text{ mA}$)	Reg _{line}	_	1.5	30	mV				
Load Regulation (I _{ref} = 1.0 to 20 mA)	Reg _{load}	_	16	30	mV				
Output Short Circuit Current (Note 5)	I _{SC}	40	75	_	mA				
Reference Under Voltage Lockout Threshold	V_{th}	4.0	4.5	5.0	V				
ERROR AMPLIFIER									
Input Offset Voltage (Note 4)	V _{IO}	-	0.4	10	mV				
Input Offset Current (Note 4)	I _{IO}	_	8.0	500	nA				
Input Bias Current (Note 4)	I _{IB}	_	-46	-1000	nA				
Input Common Mode Voltage Range	V _{ICR}	(0 V to V _{ref})			V				
Open Loop Voltage Gain (V _O = 3.0 V, R _L = 15 k)	A _{VOL}	70	80	_	dB				
Input Common Mode Rejection Ratio	CMRR	55	86	_	dB				
Power Supply Rejection Ratio (V _{CC} = V _C = 10 to 30 V)	PSRR	65	105	_	dB				

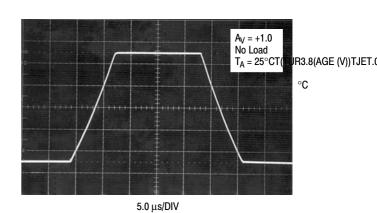
- 1. The input common mode voltage or input signal voltage should not be allowed to go negative by more than 0.3 V.
- The compliance voltage must not exceed the range of -0.3 to V_{ref}.
 NCV33035: T_{low} = -40°C, T_{high} = 125°C. Guaranteed by design. NCV prefix is for automotive and other applications requiring site and change control.
- 4. MC33035: $T_A = -40^{\circ}C$ to +85°C; NCV33035: $T_A = -40^{\circ}C$ to +125°C.
- 5. Maximum package power dissipation limits must be observed.

ELECTRICAL CHARACTERISTICS (continued) ($V_{CC} = V_C = 20 \text{ V}$, $R_T = 4.7 \text{ k}$, $C_T = 10 \text{ nF}$, $T_A = 25 ^{\circ}\text{C}$, unless otherwise noted.)

Characteristic (V _{CC} = V	Symbol	Min	Тур	Max	Unit
ERROR AMPLIFIER					
Output Voltage Swing High State (R _L = 15 k to Gnd) Low State (R _L = 15 k to V _{ref})	V _{OH} V _{OL}	4.6 -	5.3 0.5	- 1.0	V
OSCILLATOR SECTION					
Oscillator Frequency	f _{OSC}	22	25	28	kHz
Frequency Change with Voltage (V _{CC} = 10 to 30 V)	Δf _{OSC} /ΔV	_	0.01	5.0	%
Sawtooth Peak Voltage	V _{OSC(P)}	_	4.1	4.5	V
Sawtooth Valley Voltage	V _{OSC(V)}	1.2	1.5	_	V
LOGIC INPUTS	000(1)	<u> </u>			
Input Threshold Voltage (Pins 3, 4, 5, 6, 7, 22, 23) High State Low State	V _{IH} V _{IL}	3.0	2.2 1.7	- 0.8	V
Sensor Inputs (Pins 4, 5, 6) High State Input Current ($V_{IH} = 5.0 \text{ V}$) Low State Input Current ($V_{IL} = 0 \text{ V}$)	I _{IH}	-150 -600	-70 -337	-20 -150	μΑ
Forward/Reverse, $60^{\circ}/\overline{120^{\circ}}$ Select (Pins 3, 22, 23) High State Input Current (V _{IH} = 5.0 V) Low State Input Current (V _{IL} = 0 V)	l _{IH}	-75 -300	-36 -175	–10 –75	μΑ
Output Enable High State Input Current ($V_{IH} = 5.0 \text{ V}$) Low State Input Current ($V_{IL} = 0 \text{ V}$)	l _{IH}	-60 -60	-29 -29	-10 -10	μΑ
CURRENT-LIMIT COMPARATOR					
Threshold Voltage	V_{th}	85	101	115	mV
Input Common Mode Voltage Range	V _{ICR}	_	3.0	_	V
Input Bias Current	I _{IB}	_	-0.9	-5.0	μΑ
OUTPUTS AND POWER SECTIONS					
Top Drive Output Sink Saturation (I _{sink} = 25 mA)	V _{CE(sat)}	-	0.5	1.5	٧
Top Drive Output Off–State Leakage (V _{CE} = 30 V)	I _{DRV(leak)}	_	0.06	100	μΑ
Top Drive Output Switching Time ($C_L = 47 \text{ pF}, R_L = 1.0 \text{ k}$) Rise Time Fall Time	t _r		107 26	300 300	ns
Bottom Drive Output Voltage High State (V_{CC} = 20 V, V_{C} = 30 V, I_{source} = 50 mA) Low State (V_{CC} = 20 V, V_{C} = 30 V, I_{sink} = 50 mA)	V _{OH} V _{OL}	(V _{CC} -2.0)	(V _{CC} -1.1) 1.5	- 2.0	٧
Bottom Drive Output Switching Time ($C_L = 1000 \text{ pF}$) Rise Time Fall Time	t _r t _f	- -	38 30	200 200	ns
Fault Output Sink Saturation (I _{sink} = 16 mA)	V _{CE(sat)}	-	225	500	mV
Fault Output Off-State Leakage (V _{CE} = 20 V)	I _{FLT(leak)}	-	1.0	100	μΑ
Under Voltage Lockout Drive Output Enabled (V_{CC} or V_{C} Increasing) Hysteresis	V _{th(on)} V _H	8.2 0.1	8.9 0.2	10 0.3	٧
Power Supply Current Pin 17 ($V_{CC} = V_C = 20 \text{ V}$) Pin 17 ($V_{CC} = 20 \text{ V}$, $V_C = 30 \text{ V}$) Pin 18 ($V_{CC} = V_C = 20 \text{ V}$) Pin 18 ($V_{CC} = 20 \text{ V}$, $V_C = 30 \text{ V}$)	I _{CC}	- - -	12 14 3.5 5.0	16 20 6.0 10	mA

V_{sat}, OUTPUT SATURATION VOLTAGE (V)





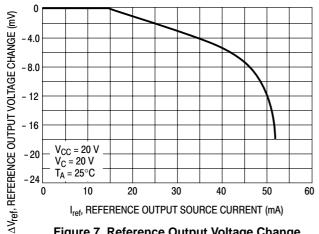


Figure 7. Reference Output Voltage Change versus Output Source Current

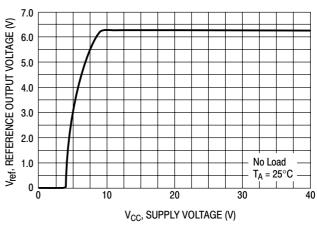


Figure 8. Reference Output Voltage versus Supply Voltage

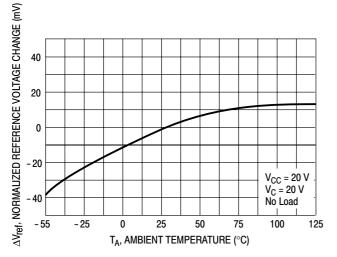


Figure 9. Reference Output Voltage versus Temperature

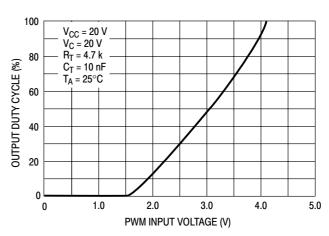


Figure 10. Output Duty Cycle versus PWM Input Voltage

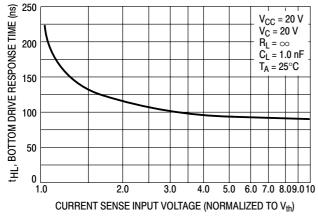


Figure 11. Bottom Drive Response Time versus Current Sense Input Voltage

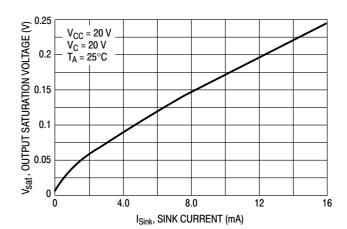


Figure 12. Fault Output Saturation versus Sink Current

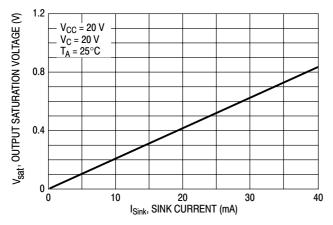


Figure 13. Top Drive Output Saturation Voltage versus Sink Current

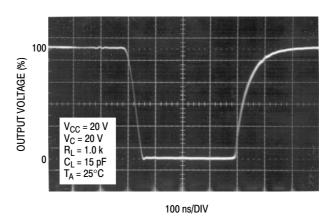


Figure 14. Top Drive Output Waveform

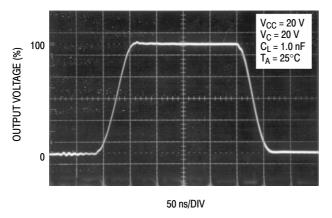


Figure 15. Bottom Drive Output Waveform

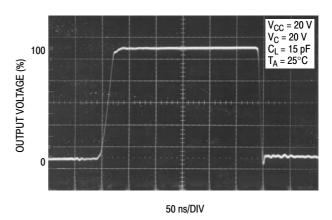


Figure 16. Bottom Drive Output Waveform

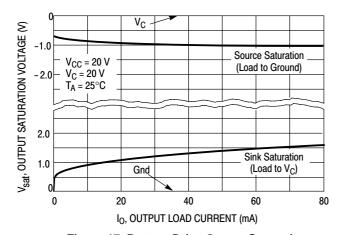


Figure 17. Bottom Drive Output Saturation Voltage versus Load Current

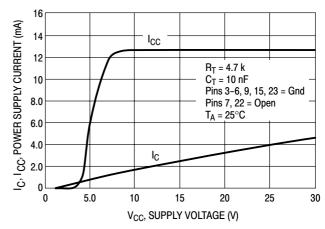


Figure 18. Power and Bottom Drive Supply Current versus Supply Voltage

PIN FUNCTION DESCRIPTION

Pin	Symbol	Description
1, 2, 24	B _T , A _T , C _T	These three open collector Top Drive outputs are designed to drive the external upper power switch transistors.
3	Fwd/Rev	The Forward/Reverse Input is used to change the direction of motor rotation.
4, 5, 6	S _A , S _B , S _C	These three Sensor Inputs control the commutation sequence.
7	Output Enable	A logic high at this input causes the motor to run, while a low causes it to coast.
8	Reference Output	This output provides charging current for the oscillator timing capacitor C _T and a reference for the error amplifier. It may also serve to furnish sensor power.
9	Current Sense Noninverting Input	A 100 mV signal, with respect to Pin 15, at this input terminates output switch conduction during a given oscillator cycle. This pin normally connects to the top side of the current sense resistor.
10	Oscillator	The Oscillator frequency is programmed by the values selected for the timing components, R_{T} and C_{T} .
11	Error Amp Noninverting Input	This input is normally connected to the speed set potentiometer.
12	Error Amp Inverting Input	This input is normally connected to the Error Amp Output in open loop applications.
13	Error Amp Out/PWM Input	This pin is available for compensation in closed loop applications.
14	Fault Output	This open collector output is active low during one or more of the following conditions: Invalid Sensor Input code, Enable Input at logic 0, Current Sense Input greater than 100 mV (Pin 9 with respect to Pin 15), Undervoltage Lockout activation, and Thermal Shutdown.
15	Current Sense Inverting Input	Reference pin for internal 100 mV threshold. This pin is normally connected to the bottom side of the current sense resistor.
16	Gnd	This pin supplies a ground for the control circuit and should be referenced back to the power source ground.
17	Vcc	This pin is the positive supply of the control IC. The controller is functional over a minimum V_{CC} range of 10 to 30 V.
18	Vc	The high state (V_{OH}) of the Bottom Drive Outputs is set by the voltage applied to this pin. The controller is operational over a minimum V_C range of 10 to 30 V.
19, 20, 21	C _B , B _B , A _B	These three totem pole Bottom Drive Outputs are designed for direct drive of the external bottom power switch transistors.
22	60°/120° Select	The electrical state of this pin configures the control circuit operation for either 60° (high state) or 120° (low state) sensor electrical phasing inputs.
23	Brake	A logic low state at this input allows the motor to run, while a high state does not allow motor operation and if operating causes rapid deceleration.

INTRODUCTION

The MC33035 is one of a series of high performance monolithic DC brushless motor controllers produced by Motorola. It contains all of the functions required to implement a full–featured, open loop, three or four phase motor control system. In addition, the controller can be made to operate DC brush motors. Constructed with Bipolar Analog technology, it offers a high degree of performance and ruggedness in hostile industrial environments. The MC33035 contains a rotor position decoder for proper commutation sequencing, a temperature compensated reference capable of supplying a sensor power, a frequency programmable sawtooth oscillator, a fully accessible error amplifier, a pulse width modulator comparator, three open collector top drive outputs, and three high current totem pole bottom driver outputs ideally suited for driving power MOSFETs.

Included in the MC33035 are protective features consisting of undervoltage lockout, cycle-by-cycle current limiting with a selectable time delayed latched shutdown mode, internal thermal shutdown, and a unique fault output that can easily be interfaced to a microprocessor controller.

Typical motor control functions include open loop speed control, forward or reverse rotation, run enable, and dynamic braking. In addition, the MC33035 has a $60^{\circ}/\overline{120^{\circ}}$ select pin which configures the rotor position decoder for either 60° or 120° sensor electrical phasing inputs.

FUNCTIONAL DESCRIPTION

A representative internal block diagram is shown in Figure 19 with various applications shown in Figures 36, 38, 39, 43, 45, and 46. A discussion of the features and function of each of the internal blocks given below is referenced to Figures 19 and 36.

Rotor Position Decoder

An internal rotor position decoder monitors the three sensor inputs (Pins 4, 5, 6) to provide the proper sequencing of the top and bottom drive outputs. The sensor inputs are designed to interface directly with open collector type Hall Effect switches or opto slotted couplers. Internal pull-up resistors are included to minimize the required number of external components. The inputs are TTL compatible, with their thresholds typically at 2.2 V. The MC33035 series is designed to control three phase motors and operate with four of the most common conventions of sensor phasing. A $60^{\circ}/\overline{120}^{\circ}$ Select (Pin 22) is conveniently provided and affords the MC33035 to configure itself to control motors having either 60°, 120°, 240° or 300° electrical sensor phasing. With three sensor inputs there are eight possible input code combinations, six of which are valid rotor positions. The remaining two codes are invalid and are usually caused by an open or shorted sensor line. With six valid input codes, the decoder can resolve the motor rotor position to within a window of 60 electrical degrees.

The Forward/Reverse input (Pin 3) is used to change the direction of motor rotation by reversing the voltage across

the stator winding. When the input changes state, from high to low with a given sensor input code (for example 100), the enabled top and bottom drive outputs with the same alpha designation are exchanged (A_T to A_B , B_T to B_B , C_T to C_B). In effect, the commutation sequence is reversed and the motor changes directional rotation.

Motor on/off control is accomplished by the Output Enable (Pin 7). When left disconnected, an internal 25 μ A current source enables sequencing of the top and bottom drive outputs. When grounded, the top drive outputs turn off and the bottom drives are forced low, causing the motor to coast and the Fault output to activate.

Dynamic motor braking allows an additional margin of safety to be designed into the final product. Braking is accomplished by placing the Brake Input (Pin 23) in a high state. This causes the top drive outputs to turn off and the bottom drives to turn on, shorting the motor-generated back EMF. The brake input has unconditional priority over all other inputs. The internal 40 k Ω pull-up resistor simplifies interfacing with the system safety-switch by insuring brake activation if opened or disconnected. The commutation logic truth table is shown in Figure 20. A four input NOR gate is used to monitor the brake input and the inputs to the three top drive output transistors. Its purpose is to disable braking until the top drive outputs attain a high state. This helps to prevent simultaneous conduction of the top and bottom power switches. In half wave motor drive applications, the top drive outputs are not required and are normally left disconnected. Under these conditions braking will still be accomplished since the NOR gate senses the base voltage to the top drive output transistors.

Error Amplifier

A high performance, fully compensated error amplifier with access to both inputs and output (Pins 11, 12, 13) is provided to facilitate the implementation of closed loop motor speed control. The amplifier features a typical DC voltage gain of 80 dB, 0.6 MHz gain bandwidth, and a wide input common mode voltage range that extends from ground to $V_{\rm ref}$. In most open loop speed control applications, the amplifier is configured as a unity gain voltage follower with the noninverting input connected to the speed set voltage source. Additional configurations are shown in Figures 31 through 35.

Oscillator

The frequency of the internal ramp oscillator is programmed by the values selected for timing components R_T and C_T . Capacitor C_T is charged from the Reference Output (Pin 8) through resistor R_T and discharged by an internal discharge transistor. The ramp peak and valley voltages are typically 4.1 V and 1.5 V respectively. To provide a good compromise between audible noise and output switching efficiency, an oscillator frequency in the range of 20 to 30 kHz is recommended. Refer to Figure 1 for component selection.

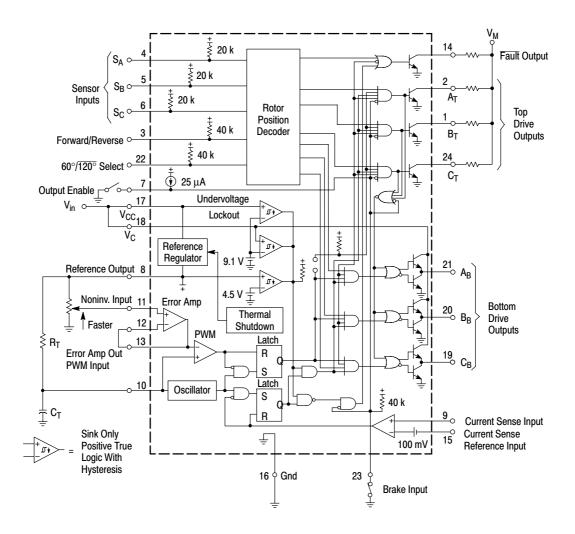


Figure 19. Representative Block Diagram

	Outputs (Note 3)					Inputs (Note 2)											
		ives	om Dr	Bott	es	p Driv	To					te 4)	ng (No	Phasii	ctrical	or Ele	Sens
	Fault	СВ	B _B	A _B	C _T	B _T	A _T	Current Sense	Brake	Enable	F/R	Sc	120° S _B	SA	Sc	60° S _B	S _A
(Note 5) F/R = 1	1 1 1 1 1 1	1 1 0 0 0	0 0 0 0 1 1	0 0 1 1 0 0	1 1 1 0 0	1 0 0 1 1	0 1 1 1 1 0	0 0 0 0 0	0 0 0 0 0	1 1 1 1 1	1 1 1 1 1	0 0 0 1 1	0 1 1 1 0 0	1 1 0 0 0	0 0 1 1 1 0	0 1 1 1 0 0	1 1 1 0 0
(Note 5) F/R = 0	1 1 1 1 1 1	0 0 0 1 1	0 1 1 0 0	1 0 0 0 0	0 0 1 1 1	1 1 1 1 0	1 1 0 0 1	0 0 0 0 0	0 0 0 0 0	1 1 1 1 1	0 0 0 0 0	0 0 0 1 1	0 1 1 1 0 0	1 1 0 0 0	0 0 1 1 1 0	0 1 1 1 0 0	1 1 1 0 0
(Note 6) Brake = 0	0	0	0	0	1	1 1	1 1	X X	0	X	X X	1	1 0	1 0	1	0	1
(Note 7) Brake = 1	0	1	1	1 1	1 1	1 1	1 1	X X	1 1	X	X	1	1 0	1 0	1	0 1	1 0
(Note 8)	1	1	1	1	1	1	1	Х	1	1	Х	V	V	V	V	V	V
(Note 9)	0	1	1	1	1	1	1	Х	1	0	Х	V	V	V	V	V	V
(Note 10)	0	0	0	0	1	1	1	Х	0	0	Х	V	V	V	V	V	V



NOTES: 1. V = Any one of six valid sensor or drive combinations X = Don't care.

- The digital inputs (Pins 3, 4, 5, 6, 7, 22, 23) are all TTL compatible. The current sense input (Pin 9) has a 100 mV threshold with respect to Pin 15.
 A logic 0 for this input is defined as < 85 mV. and a logic 1 is > 115 mV.
- 3. The fault and top drive outputs are open collector design and active in the low (0) state.
- 4. With 60°/120° select (Pin 22) in the high (1) state, configuration is for 60° sensor electrical phasing inputs. With Pin 22 in low (0) state, configuration is for 120° sensor electrical phasing inputs.
- 5. Valid 60° or 120° sensor combinations for corresponding valid top and bottom drive outputs.
- 6. Invalid sensor inputs with brake = 0; All top and bottom drives off, Fault low
- 7. Invalid sensor inputs with brake = 1; All top drives off, all bottom drives on, Fault low.
- 8. Valid 60° or 120° sensor inputs with brake = 1; All top drives off, all bottom drives on, Fault high.
- 9. Valid sensor inputs with brake = 1 and enable = 0; All top drives off, all bottom drives on, Fault low.
- 10. Valid sensor inputs with brake = 0 and enable = 0; All top and bottom drives off, Fault low.
- 11. All bottom drives off, Fault low.

Figure 20. Three Phase, Six Step Commutation Truth Table (Note 1)

Pulse Width Modulator

The use of pulse width modulation provides an energy efficient method of controlling the motor speed by varying the average voltage applied to each stator winding during the commutation sequence. As C_T discharges, the oscillator sets both latches, allowing conduction of the top and bottom drive outputs. The PWM comparator resets the upper latch, terminating the bottom drive output conduction when the positive—going ramp of C_T becomes greater than the error amplifier output. The pulse width modulator timing diagram is shown in Figure 21. Pulse width modulation for speed control appears only at the bottom drive outputs.

Current Limit

Continuous operation of a motor that is severely over-loaded results in overheating and eventual failure. This destructive condition can best be prevented with the use of cycle-by-cycle current limiting. That is, each on-cycle is treated as a separate event. Cycle-by-cycle current limiting is accomplished by monitoring the stator current build-up each time an output switch conducts, and upon

sensing an over current condition, immediately turning off the switch and holding it off for the remaining duration of oscillator ramp—up period. The stator current is converted to a voltage by inserting a ground—referenced sense resistor R_S (Figure 36) in series with the three bottom switch transistors (Q₄, Q₅, Q₆). The voltage developed across the sense resistor is monitored by the Current Sense Input (Pins 9 and 15), and compared to the internal 100 mV reference. The current sense comparator inputs have an input common mode range of approximately 3.0 V. If the 100 mV current sense threshold is exceeded, the comparator resets the lower sense latch and terminates output switch conduction. The value for the current sense resistor is:

$$R_S = \frac{0.1}{I_{stator(max)}}$$

The Fault output activates during an over current condition. The dual-latch PWM configuration ensures that only one single output conduction pulse occurs during any given oscillator cycle, whether terminated by the output of the error amp or the current limit comparator.

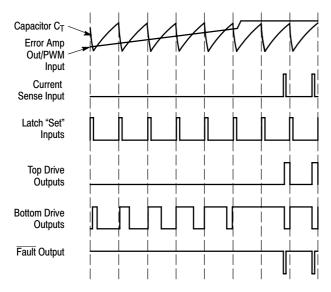
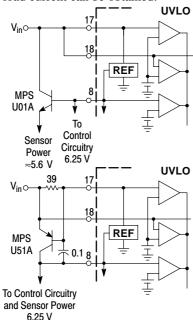


Figure 21. Pulse Width Modulator Timing Diagram Reference

The on–chip 6.25 V regulator (Pin 8) provides charging current for the oscillator timing capacitor, a reference for the error amplifier, and can supply 20 mA of current suitable for directly powering sensors in low voltage applications. In higher voltage applications, it may become necessary to transfer the power dissipated by the regulator off the IC. This is easily accomplished with the addition of an external pass transistor as shown in Figure 22. A 6.25 V reference level was chosen to allow implementation of the simpler NPN circuit, where $V_{\rm ref}-V_{\rm BE}$ exceeds the minimum voltage required by Hall Effect sensors over temperature. With proper transistor selection and adequate heatsinking, up to one amp of load current can be obtained.



The NPN circuit is recommended for powering Hall or opto sensors, where the output voltage temperature coefficient is not critical. The PNP circuit is slightly more complex, but is also more accurate over temperature. Neither circuit has current limiting.

Figure 22. Reference Output Buffers

Undervoltage Lockout

A triple Undervoltage Lockout has been incorporated to prevent damage to the IC and the external power switch transistors. Under low power supply conditions, it guarantees that the IC and sensors are fully functional, and that there is sufficient bottom drive output voltage. The positive power supplies to the IC (V_{CC}) and the bottom drives (V_C) are each monitored by separate comparators that have their thresholds at 9.1 V. This level ensures sufficient gate drive necessary to attain low R_{DS(on)} when driving standard power MOSFET devices. When directly powering the Hall sensors from the reference, improper sensor operation can result if the reference output voltage falls below 4.5 V. A third comparator is used to detect this condition. If one or more of the comparators detects an undervoltage condition, the Fault Output is activated, the top drives are turned off and the bottom drive outputs are held in a low state. Each of the comparators contain hysteresis to prevent oscillations when crossing their respective thresholds.

Fault Output

The open collector Fault Output (Pin 14) was designed to provide diagnostic information in the event of a system malfunction. It has a sink current capability of 16 mA and can directly drive a light emitting diode for visual indication. Additionally, it is easily interfaced with TTL/CMOS logic for use in a microprocessor controlled system. The Fault Output is active low when one or more of the following conditions occur:

- 1) Invalid Sensor Input code
- 2) Output Enable at logic [0]
- 3) Current Sense Input greater than 100 mV
- 4) Undervoltage Lockout, activation of one or more of the comparators
- 5) Thermal Shutdown, maximum junction temperature being exceeded

This unique output can also be used to distinguish between motor start-up or sustained operation in an overloaded condition. With the addition of an RC network between the Fault Output and the enable input, it is possible to create a time-delayed latched shutdown for overcurrent. The added circuitry shown in Figure 23 makes easy starting of motor systems which have high inertial loads by providing additional starting torque, while still preserving overcurrent protection. This task is accomplished by setting the current limit to a higher than nominal value for a predetermined time. During an excessively long overcurrent condition, capacitor C_{DLY} will charge, causing the enable input to cross its threshold to a low state. A latch is then formed by the positive feedback loop from the Fault Output to the Output Enable. Once set, by the Current Sense Input, it can only be reset by shorting C_{DLY} or cycling the power supplies.

Drive Outputs

The three top drive outputs (Pins 1, 2, 24) are open collector NPN transistors capable of sinking 50 mA with a minimum breakdown of 30 V. Interfacing into higher voltage applications is easily accomplished with the circuits shown in Figures 24 and 25.

The three totem pole bottom drive outputs (Pins 19, 20, 21) are particularly suited for direct drive of N–Channel MOSFETs or NPN bipolar transistors (Figures 26, 27, 28 and 29). Each output is capable of sourcing and sinking up to 100 mA. Power for the bottom drives is supplied from V_C (Pin 18). This separate supply input allows the designer added flexibility in tailoring the drive voltage, independent

of V_{CC} . A zener clamp should be connected to this input when driving power MOSFETs in systems where V_{CC} is greater than 20 V so as to prevent rupture of the MOSFET gates.

The control circuitry ground (Pin 16) and current sense inverting input (Pin 15) must return on separate paths to the central input source ground.

Thermal Shutdown

Internal thermal shutdown circuitry is provided to protect the IC in the event the maximum junction temperature is exceeded. When activated, typically at 170°C, the IC acts as though the Output Enable was grounded.

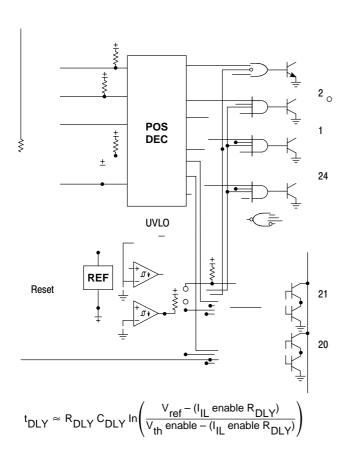


Figure 23. Timed Delayed Latched Over Current Shutdown

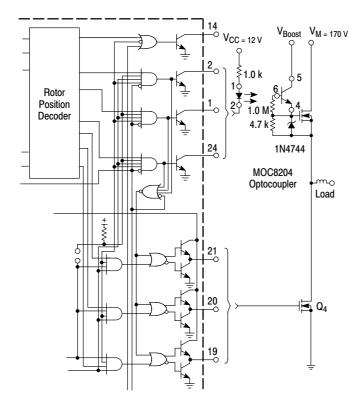
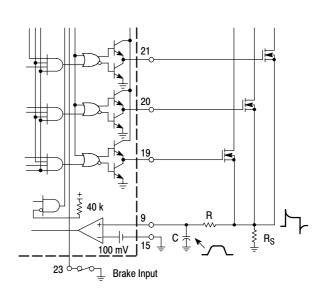
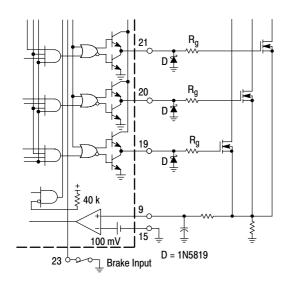


Figure 25. High Voltage Interface with N-Channel Power MOSFETs



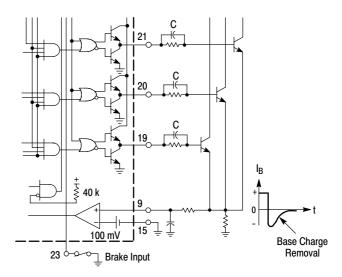
The addition of the RC filter will eliminate current–limit instability caused by the leading edge spike on the current waveform. Resistor R_S should be a low inductance type.

Figure 26. Current Waveform Spike Suppression



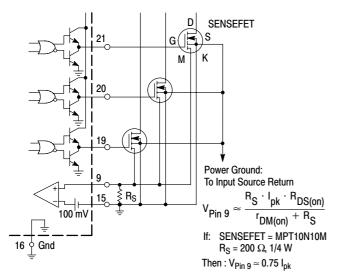
Series gate resistor ${\rm R_g}$ will dampen any high frequency oscillations caused by the MOSFET input capacitance and any series wiring induction in the gate–source circuit. Diode D is required if the negative current into the Bottom Drive Outputs exceeds 50 mÅ.

Figure 27. MOSFET Drive Precautions



The totem–pole output can furnish negative base current for enhanced transistor turn–off, with the addition of capacitor C.

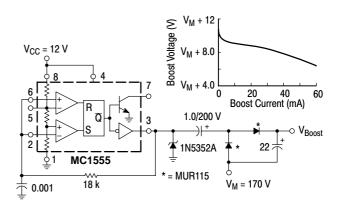
Figure 28. Bipolar Transistor Drive



Control Circuitry Ground (Pin 16) and Current Sense Inverting Input (Pin 15) must return on separate paths to the Central Input Source Ground.

Virtually lossless current sensing can be achieved with the implementation of SENSEFET power switches.

Figure 29. Current Sensing Power MOSFETs



This circuit generates $V_{\mbox{\footnotesize Boost}}$ for Figure 25.

Figure 30. High Voltage Boost Supply

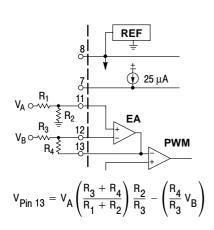
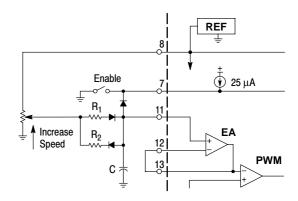
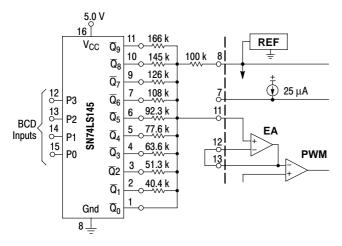


Figure 31. Differential Input Speed Controller

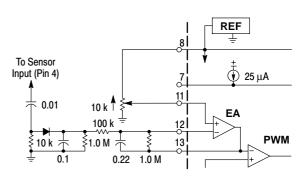


Resistor R_1 with capacitor C sets the acceleration time constant while R_2 controls the deceleration. The values of R_1 and R_2 should be at least ten times greater than the speed set potentiometer to minimize time constant variations with different speed settings.

Figure 32. Controlled Acceleration/Deceleration



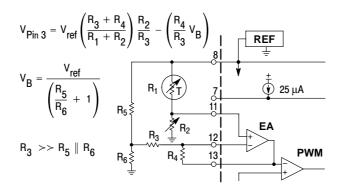
The SN74LS145 is an open collector BCD to One of Ten decoder. When connected as shown, input codes 0000 through 1001 steps the PWM in increments of approximately 10% from 0 to 90% on–time. Input codes 1010 through 1111 will produce 100% on–time or full motor speed.



The rotor position sensors can be used as a tachometer. By differentiating the positive–going edges and then integrating them over time, a voltage proportional to speed can be generated. The error amp compares this voltage to that of the speed set to control the PWM.

Figure 33. Digital Speed Controller

Figure 34. Closed Loop Speed Control



This circuit can control the speed of a cooling fan proportional to the difference between the sensor and set temperatures. The control loop is closed as the forced air cools the NTC thermistor. For controlled heating applications, exchange the positions of R_1 and R_2 .

Figure 35. Closed Loop Temperature Control

Three Pha

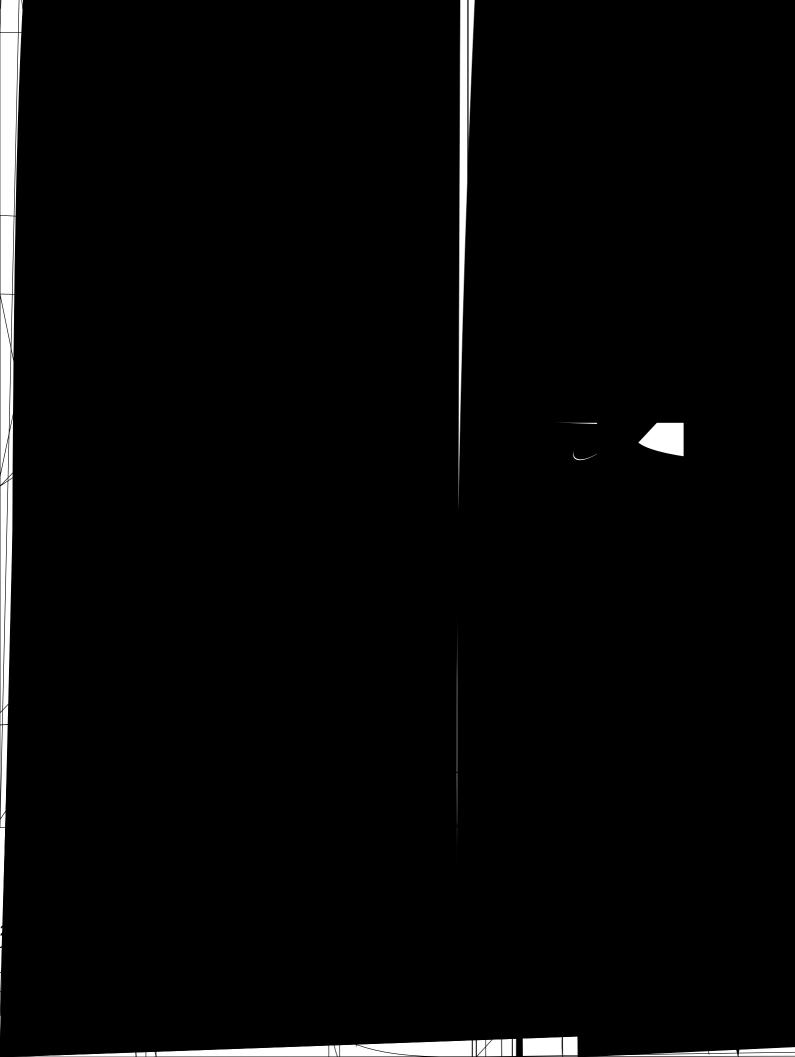
The thr full-featu step dri Darlingt Each of diode th to the delta q if spli one to poles the s curr spik cau by Us

nown aty.

Rotor Electrical Position (Degrees) 0 60 120 180 240 300 360 420 480 540 600 660 720 \mathbf{S}_{A} **Sensor Inputs** S_B 60°/120° Select Pin Open $\boldsymbol{s}_{\boldsymbol{c}}$ 100 110 111 011 001 000 100 110 111 011 001 000 Code $\mathbf{S}_{\mathbf{A}}$ **Sensor Inputs** S_B 60°/120° Select Pin $\mathbf{s}_{\mathbf{c}}$ Grounded Code 100 110 010 011 001 101 100 110 010 011 001 101 A_T **Top Drive** \mathbf{B}_{T} Outputs C_T A_B **Bottom Drive** B_B Outputs C_{B} Conducting **Power Switch** $Q_2 + Q_6$ $Q_3 + Q_4 \mid Q_3 + Q_5 \mid Q_1 + Q_5 \mid Q_1 + Q_6 \mid Q_2 + Q_6 \mid Q_2 + Q_4 \mid Q_3 + Q_4 \mid Q_3 + Q_5 \mid Q_1 + Q_5 \mid Q_1 + Q_5 \mid Q_2 + Q_6 \mid Q_3 + Q_4 \mid Q_3 + Q_6 \mid Q_5 + Q_6 \mid Q_5$ **Transistors** 0 **Motor Drive** В 0 Current С 0 Full Speed (No PWM) Reduced Speed (\approx 50% PWM)

Figure 37. Three Phase, Six Step, Full Wave Commutation Waveforms

Fwd/Rev = 1

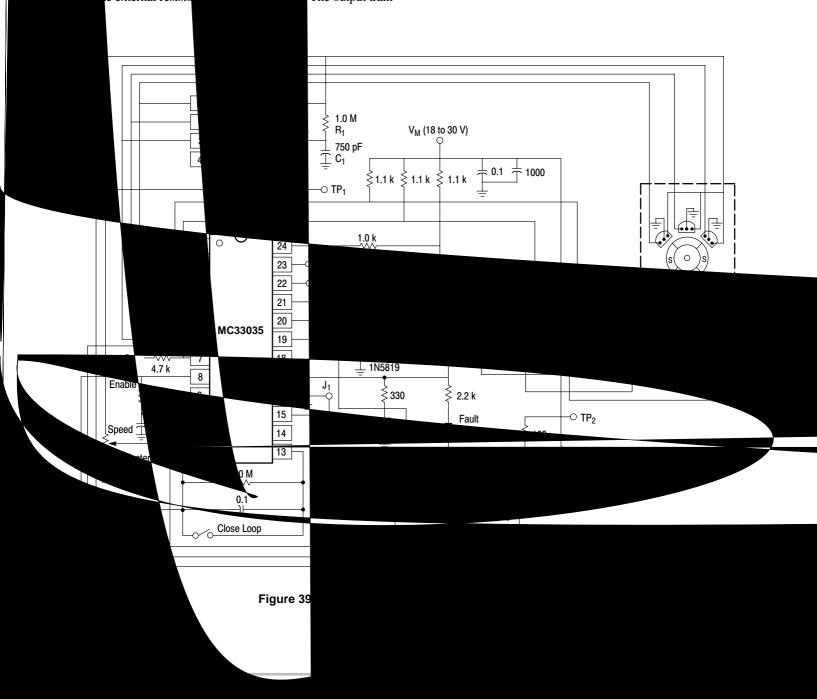


ree Phase Clos

The MC33035, ptor speed control MC33035 requitor speed. Tradit ans of a tachome tage. Figure 39:233039, powered 233035, is used to nout the need of sor signals used poding are utilize ative going transfers e sensor lines care of defined ample external resistor.

le of open loop or speed control, oportional to the accomplished by r speed feedback on whereby an ace (Pin 8) of the feedback voltage The same Hall r rotor position very positive or r signals on any roduce an output n, as determined The output train of pulses at Pin 5 of the MC33039 are integrated by the error amplifier of the MC33035 configured as an integrator to produce a DC voltage level which is proportional to the motor speed. This speed proportional voltage establishes the PWM reference level at Pin 13 of the MC33035 motor controller and closes the feedback loop. The MC33035 outputs drive a TMOS power MOSFET 3–phase bridge. High currents can be expected during conditions of start—up, breaking, and change of direction of the motor.

The system shown in Figure 39 is designed for a motor having 120/240 degrees Hall sensor electrical phasing. The system can easily be modified to accommodate 60/300 degree Hall sensor electrical phasing by removing the jumper (J₂) at Pin 22 of the MC33035.



Sensor Phasing Comparison

There are four conventions used to establish the relative phasing of the sensor signals in three phase motors. With six step drive, an input signal change must occur every 60 electrical degrees; however, the relative signal phasing is dependent upon the mechanical sensor placement. A comparison of the conventions in electrical degrees is shown in Figure 40. From the sensor phasing table in Figure 41, note that the order of input codes for 60° phasing is the reverse of 300°. This means the MC33035, when configured for 60° sensor electrical phasing, will operate a motor with either 60° or 300° sensor electrical phasing, but resulting in opposite directions of rotation. The same is true for the part when it is configured for 120° sensor electrical phasing; the motor will operate equally, but will result in opposite directions of rotation for 120° for 240° conventions.

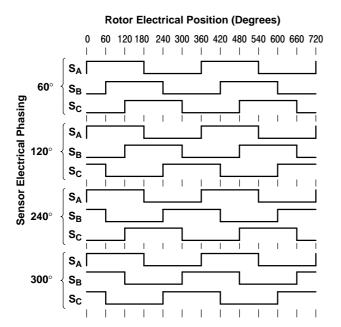


Figure 40. Sensor Phasing Comparison

	Sensor Electrical Phasing (Degrees)										
	60°			120°			240°			300°	
SA	S _B	Sc	SA	S _B	S _C	SA	S _B	Sc	SA	S _B	S _C
1	0	0	1	0	1	1	1	0	1	1	1
1	1	0	1	0	0	1	0	0	1	1	0
1	1	1	1	1	0	1	0	1	1	0	0
0	1	1	0	1	0	0	0	1	0	0	0
0	0	1	0	1	1	0	1	1	0	0	1
0	0	0	0	0	1	0	1	0	0	1	1

Figure 41. Sensor Phasing Table

In this data sheet, the rotor position is always given in electrical degrees since the mechanical position is a function of the number of rotating magnetic poles. The relationship between the electrical and mechanical position is:

Electrical Degrees = Mechanical Degrees
$$\left(\frac{\#Rotor\ Poles}{2}\right)$$

An increase in the number of magnetic poles causes more electrical revolutions for a given mechanical revolution. General purpose three phase motors typically contain a four pole rotor which yields two electrical revolutions for one mechanical.

Two and Four Phase Motor Commutation

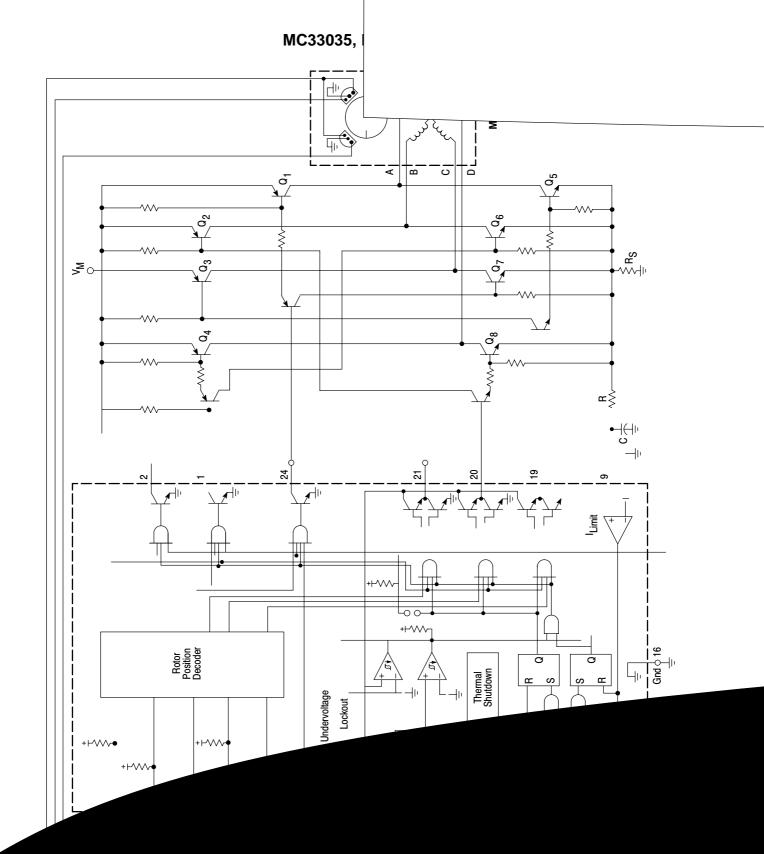
The MC33035 is also capable of providing a four step output that can be used to drive two or four phase motors. The truth table in Figure 42 shows that by connecting sensor inputs S_B and S_C together, it is possible to truncate the number of drive output states from six to four. The output power switches are connected to B_T , C_T , B_B , and C_B . Figure 43 shows a four phase, four step, full wave motor control application. Power switch transistors Q_1 through Q_8 are Darlington type, each with an internal parasitic catch diode. With four step drive, only two rotor position sensors spaced at 90 electrical degrees are required. The commutation waveforms are shown in Figure 44.

Figure 45 shows a four phase, four step, half wave motor controller. It has the same features as the circuit in Figure 38, except for the deletion of speed control and braking.

MC33035 (60°/120° Select Pin Open)									
	Inputs			Out	puts				
	Sensor Electrical Spacing* = 90°		Top Drives		es Bottom				
S _A	S_B	F/R	B _T	C _T	B _B	CB			
1	0	1	1	1	0	1			
1	1	1	0	1	0	0			
0	1	1	1	0	0	0			
0	0	1	1	1	1	0			
1	0	0	1	0	0	0			
1	1	0	1	1	1	0			
0	1	0	1	1	0	1			
0	0	0	0	1	0	0			

*With MC33035 sensor input S_B connected to S_C.

Figure 42. Two and Four Phase, Four Step, Commutation Truth Table



Rotor Electrical Position (Degrees)

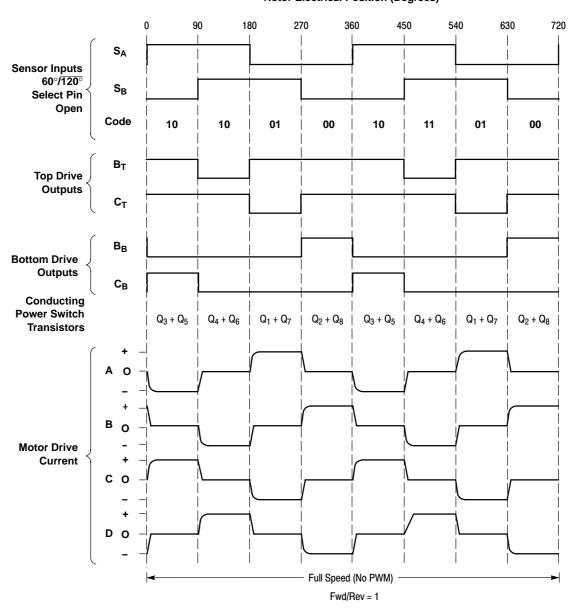


Figure 44. Four Phase, Four Step, Full Wave Motor Controller

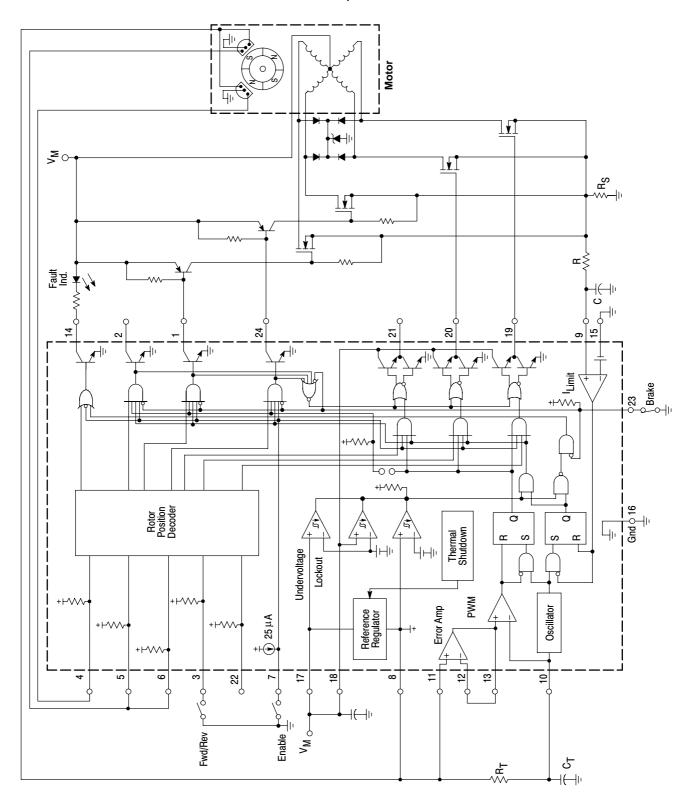


Figure 45. Four Phase, Four Step, Half Wave Motor Controller

Brush Motor Control

Though the MC33035 was designed to control brushless DC motors, it may also be used to control DC brush type motors. Figure 46 shows an application of the MC33035 driving a MOSFET H-bridge affording minimal parts count to operate a brush-type motor. Key to the operation is the input sensor code [100] which produces a top-left (Q₁) and a bottom-right (Q₃) drive when the controller's forward/reverse pin is at logic [1]; top-right (Q₄), bottom-left (Q₂) drive is realized when the Forward/Reverse pin is at logic [0]. This code supports the requirements necessary for H-bridge drive accomplishing both direction and speed control.

The controller functions in a normal manner with a pulse width modulated frequency of approximately 25 kHz. Motor speed is controlled by adjusting the voltage presented to the noninverting input of the error amplifier establishing the PWM's slice or reference level. Cycle-by-cycle current limiting of the motor current is accomplished by sensing the voltage (100 mV) across the R_S resistor to ground of the H-bridge motor current. The over current sense circuit

makes it possible to reverse the direction of the motor, using the normal forward/reverse switch, on the fly and not have to completely stop before reversing.

LAYOUT CONSIDERATIONS

Do not attempt to construct any of the brushless motor control circuits on wire–wrap or plug–in prototype boards. High frequency printed circuit layout techniques are imperative to prevent pulse jitter. This is usually caused by excessive noise pick–up imposed on the current sense or error amp inputs. The printed circuit layout should contain a ground plane with low current signal and high drive and output buffer grounds returning on separate paths back to the power supply input filter capacitor V_M . Ceramic bypass capacitors $(0.1~\mu F)$ connected close to the integrated circuit at V_{CC} , V_{C} , V_{ref} and the error amp noninverting input may be required depending upon circuit layout. This provides a low impedance path for filtering any high frequency noise. All high current loops should be kept as short as possible using heavy copper runs to minimize radiated EMI.

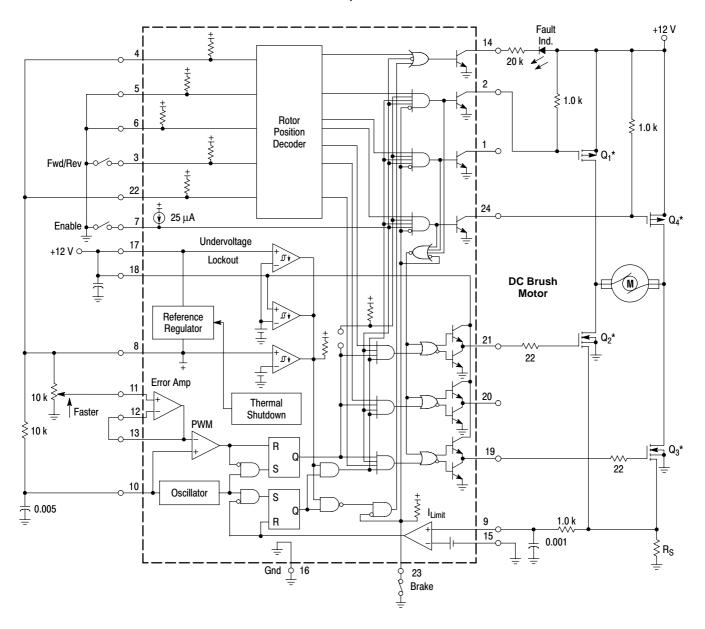


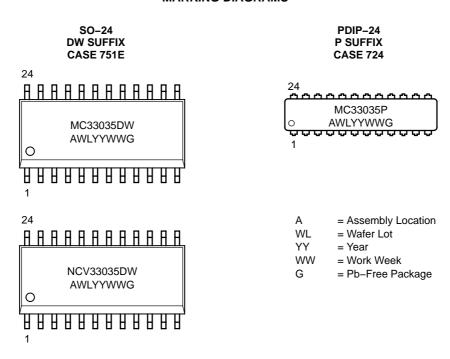
Figure 46. H-Bridge Brush-Type Controller

ORDERING INFORMATION

Device	Operating Temperature Range	Package	Shipping [†]
MC33035DW		SO-24L	30 Units / Rail
MC33035DWG		SO-24L (Pb-Free)	30 Units / Rail
MC33035DWR2		SO-24L	1000 Tape & Reel
MC33035DWR2G	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	SO-24L (Pb-Free)	1000 Tape & Reel
MC33035P		Plastic DIP	15 Units / Tube
MC33035PG		Plastic DIP (Pb–Free)	15 Units / Tube
NCV33035DWR2*		SO-24L	1000 Tape & Reel
NCV33035DWR2G*	$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	SO-24L (Pb-Free)	1000 Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

MARKING DIAGRAMS



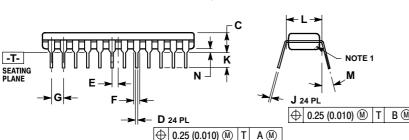
^{*}NCV33035: T_{low} = -40C, T_{high} = +125C. Guaranteed by design. NCV prefix is for automotive and other applications requiring site and change control.

PACKAGE DIMENSIONS

P SUFFIX

PLASTIC PACKAGE CASE 724-03 ISSUE D





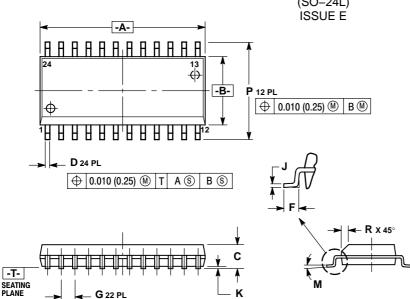
NOTES:

- CHAMFERED CONTOUR OPTIONAL.
 DIMENSION L TO CENTER OF LEADS WHEN 2. FORMED PARALLEL
- DIMENSIONING AND TOLERANCING PER ANSI
- CONTROLLING DIMENSION: INCH.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	1.230	1.265	31.25	32.13	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.020	0.38	0.51	
E	0.05	0 BSC	1.27 BSC		
F	0.040	0.060	1.02	1.52	
G	0.10	00 BSC	2.54 BSC		
J	0.007	0.012	0.18	0.30	
K	0.110	0.140	2.80	3.55	
L	0.30	0 BSC	7.62 BSC		
M	0°	15°	0°	15°	
N	0.020	0.040	0.51	1.01	

DW SUFFIX

PLASTIC PACKAGE CASE 751E-04 (SO-24L)



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M. 1982.
- CONTROLLING DIMENSION: MILLIMETER.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- 5 DIMENSION DIDOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR
 PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN
 EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION

	MILLIM	ETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	15.25	15.54	0.601	0.612	
В	7.40	7.60	0.292	0.299	
С	2.35	2.65	0.093	0.104	
D	0.35	0.49	0.014	0.019	
F	0.41	0.90	0.016	0.035	
G	1.27	BSC	0.050 BSC		
J	0.23	0.32	0.009	0.013	
K	0.13	0.29	0.005	0.011	
M	0°	8°	0°	8°	
P	10.05	10.55	0.395	0.415	
R	0.25	0.75	0.010	0.029	

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